

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	0	semi adj insulating adj gallium adj nitride adj substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/22 13:27
S2	3119	semi adj insulating adj substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 14:02
S3	7784	gallium adj nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/16 08:38
S4	79	S2 and S3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 14:02
S5	0	intrinsic same gallium adj nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 14:51
S6	2	("20020100916").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/16 15:27
S7	20	intrinsic adj gallium adj nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 15:27
S8	8	("5686738").URPN.	USPAT	OR	ON	2004/11/16 15:46

S9	64	("3683240"   "3819974"   "3829556"   "4144116"   "4153905"   "4396929"   "4473938"   "4476620"   "4589015"   "4608581"   "4615766"   "4792467"   "4819057"   "4819058"   "4855249"   "4866007"   "4897149"   "4911102"   "4918497"   "4946547"   "4946548"   "4960728"   "4966862"   "4966867"   "4983249"   "5005057"   "5006908"   "5010033"   "5015327"   "5027168"   "5042043"   "5063421"   "5068204"   "5076860"   "5093576"   "5097298"   "5117267"   "5119540"   "5122845"   "5140385"   "5173751"   "5178911"   "5182670"   "5192419"   "5200022"   "5205905"   "5210051"   "5218216"   "5237182"   "5243204"   "5248631"   "5272108"   "5290393"   "5298767"   "5304820"   "5306662"   "5307363"   "5313078"   "5323022"   "5329141"   "5334277"   "5338944"   "5359345"   "5385862").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/11/16 16:00
S10	93	boule and gallium adj nitride	US-PGPUB; USPAT; USOCR	OR	ON	2004/11/16 16:00
S11	84	(cr or chromium or molydenmum or mo or tungsten or w or cu or copper or zinc or zn or platinum or pt) and S10	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/16 08:38
S12	0	transistion adj metal and S11	US-PGPUB; USPAT; USOCR	OR	ON	2004/11/16 16:02
S13	54	dopant and S11	US-PGPUB; USPAT; USOCR	OR	ON	2004/11/16 16:09
S14	35	insulating near gallium adj nitride	US-PGPUB; USPAT; USOCR	OR	ON	2004/11/16 16:09

S15	11	("5284394"   "5344948"   "5385862"   "5398641"   "5464656"   "5602418"   "5657335"   "5786233"   "5976412"   "6080668"   "6291318").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/11/16 16:12
S16	0	("6544867").URPN.	USPAT	OR	ON	2004/11/16 16:15
S17	92934	transition adj metals	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 19:10
S18	20831	gan or gallium adj nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 19:10
S19	615	S17 and S18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 19:10
S20	248	insulating and S19	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 19:10
S21	548	(cobalt or co or copper or cu or nickel or ni) and S19	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 19:11
S22	234	S20 and S21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 19:11
S23	148	(resistance or resistivity) and S22	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 19:12
S24	116	substrate and S23	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/16 19:13

S25	3	kyma adj technologies	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 14:31
S26	2	free adj standing and S25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 14:31
S27	534	(gan or gallium adj nitride) same (co or cobalt)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 15:54
S28	28	deep and impurity and S27	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 15:54
S29	85	(gan or gallium adj nitride) same (cobalt)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 15:54
S30	0	deep and impurity and S29	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 15:54
S31	8288	gallium adj nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/16 08:38
S32	3755	(cr or chromium or molydenmum or mo or tungsten or w or cu or copper or zinc or zn or platinum or pt or co or cobalt or ni or nickel or fe or iron or mn or manganese) and S31	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/16 08:40
S33	347	(hyvpe or hydride adj vapor adj phase adj epitaxy) and S32	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/16 08:43
S34	39	semi adj insulating and S33	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/16 08:43

S35	12	diameter near4 gallium adj nitride	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/22 11:37
S36	292	diameter same gallium adj nitride	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/22 11:56
S37	78	free adj standing adj gan or free adj standing adj gallium adj nitride	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/22 11:58
S38	2863452	diameter	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/22 11:59
S39	50	S37 and S38	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/22 11:59
S40	2	("6596079").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/22 13:28